

/ Descriptions

SOT-523 N MOS
 N-CHANNEL MOSFET in a SOT-523 Plastic Package.

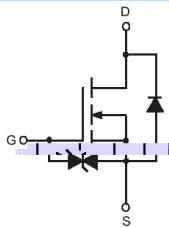
/ Features

Sensitive gate trigger current and Low Holding current.ESD protected,HF Product.

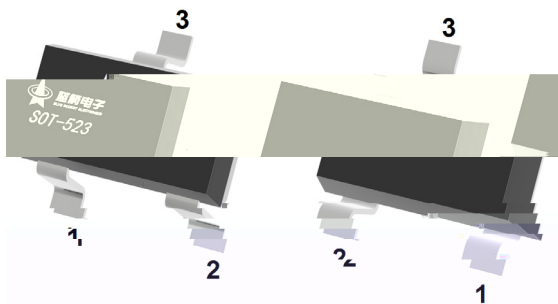
/ Applications

Intended for use in general purpose switching and phase control applications.

/ Equivalent Circuit



/ Pinning



PIN1 G

PIN 2 S

PIN 3 D

/ Marking

Marking	KN
---------	----

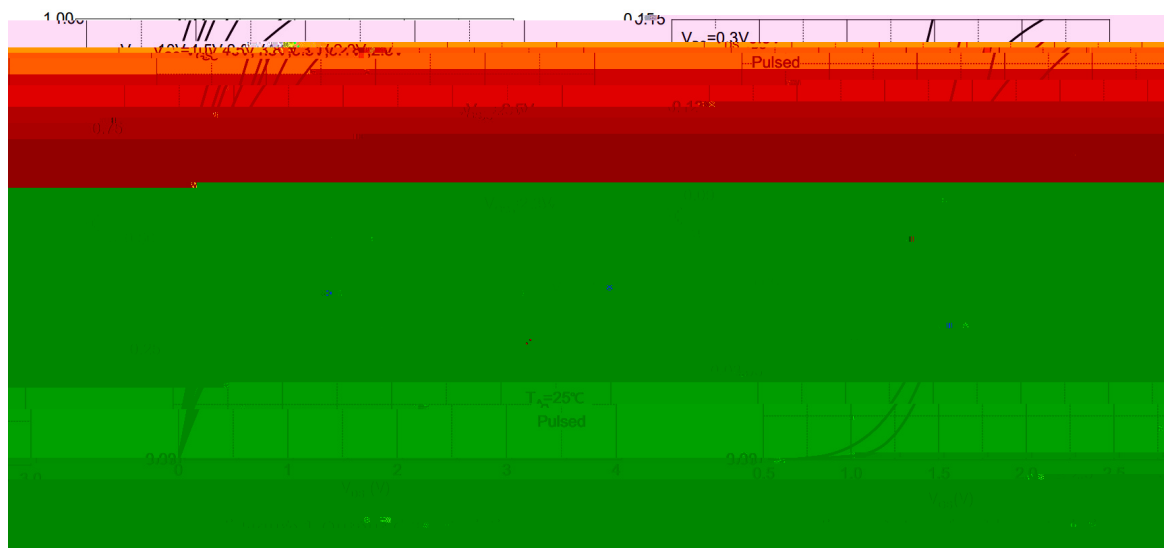
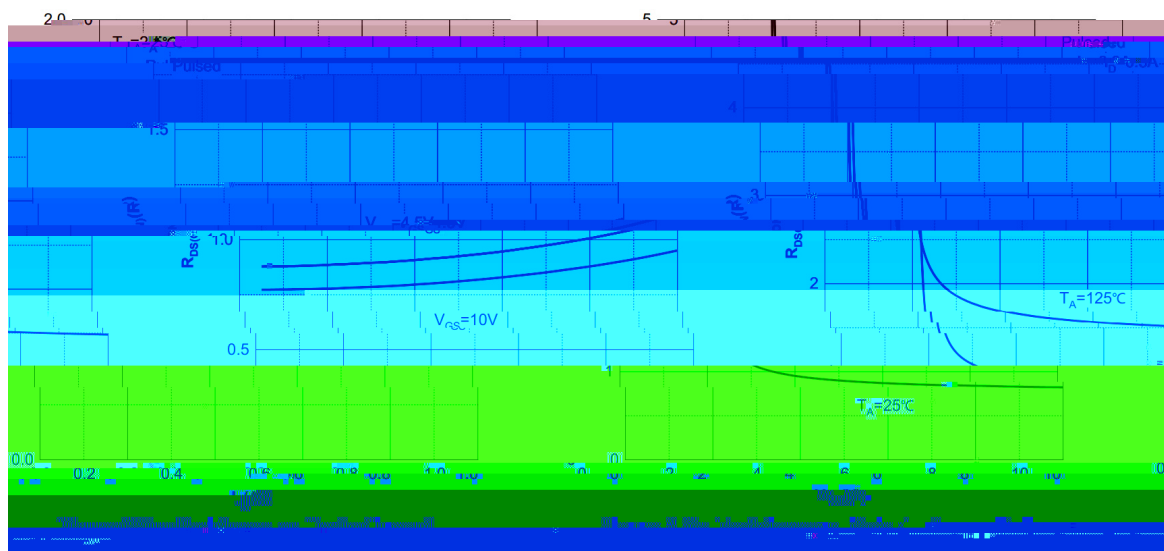
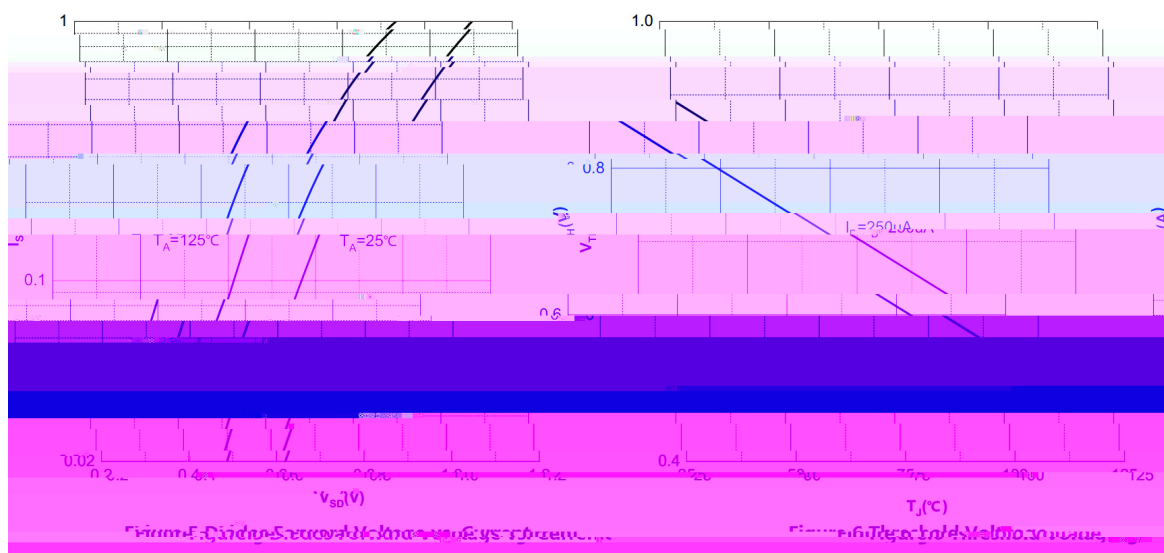
/ Absolute Maximum Ratings($T_a=25^\circ\text{C}$)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	50	V
Gate-Source Voltage	V_{GS}	± 20	V
Drain Current	I_D	300	mA
Drain Current – Pulsed	I_{DM}	1200	mA
Power Dissipation	P_D	250	mW
Junction Temperature Range	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	
Thermal Resistance from Junction to Ambient	R_{JA}	500	/W

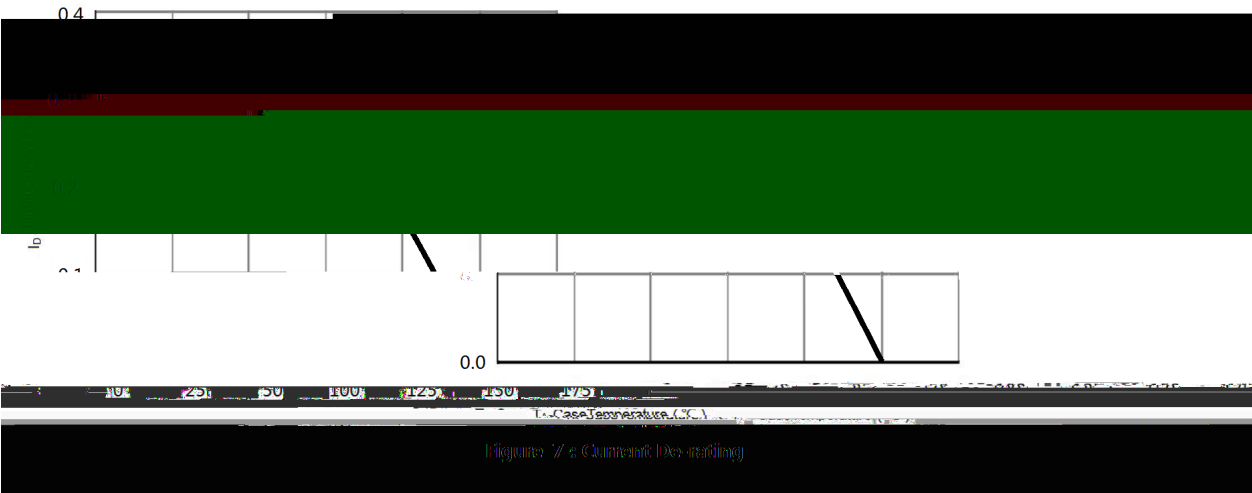
/ Electrical Characteristics($T_a=25^\circ\text{C}$)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain–Source Breakdown Voltage	V_{DSS}	$V_{GS}=0$ $I_D=250\mu\text{A}$	50			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{GS}=0$ $V_{DS}=50\text{V}$			1.0	μA
Gate-Source Leakage current	I_{GSS}	$V_{DS}=0\text{V}$ $V_{GS}=\pm 20\text{V}$			± 2	μA
Static Drain-Source On-Resistance	$R_{DS(on)(1)}$	$V_{GS}=10\text{V}$ $I_D=0.3\text{A}$		0.92	2.5	$\text{m}\Omega$
	$R_{DS(on)(2)}$	$V_{GS}=4.5\text{V}$ $I_D=0.2\text{A}$		0.98	3	$\text{m}\Omega$
	$R_{DS(on)(3)}$	$V_{GS}=2.5\text{V}$ $I_D=0.01\text{A}$		1.2	4.5	$\text{m}\Omega$
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0\text{V}$ $I_S=300\text{mA}$			1.2	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=250\mu\text{A}$	0.6	0.9	1.5	V
Input Capacitance	C_{iss}	$V_{GS}=0\text{V}$, $f=1\text{MHz}$, $V_{DS}=15\text{V}$		30		pF
Output Capacitance	C_{oss}			5.2		
Reverse Transfer Capacitance	C_{rss}			3.3		
Gate Resistance	R_g	$V_{DS}=0\text{V}$, $V_{GS}=0\text{V}$, $f=1\text{MHz}$		157		
Turn On Delay Time	$t_{d(ON)}$	$V_{GS}=5\text{V}$, $V_{DD}=5\text{V}$, $R_L=500\Omega$, $R_G=10\Omega$		15		ns
Rise Time	t_r			35		
Turn Off Delay Time	$t_{d(OFF)}$			80		
Fall Time	t_f			80		

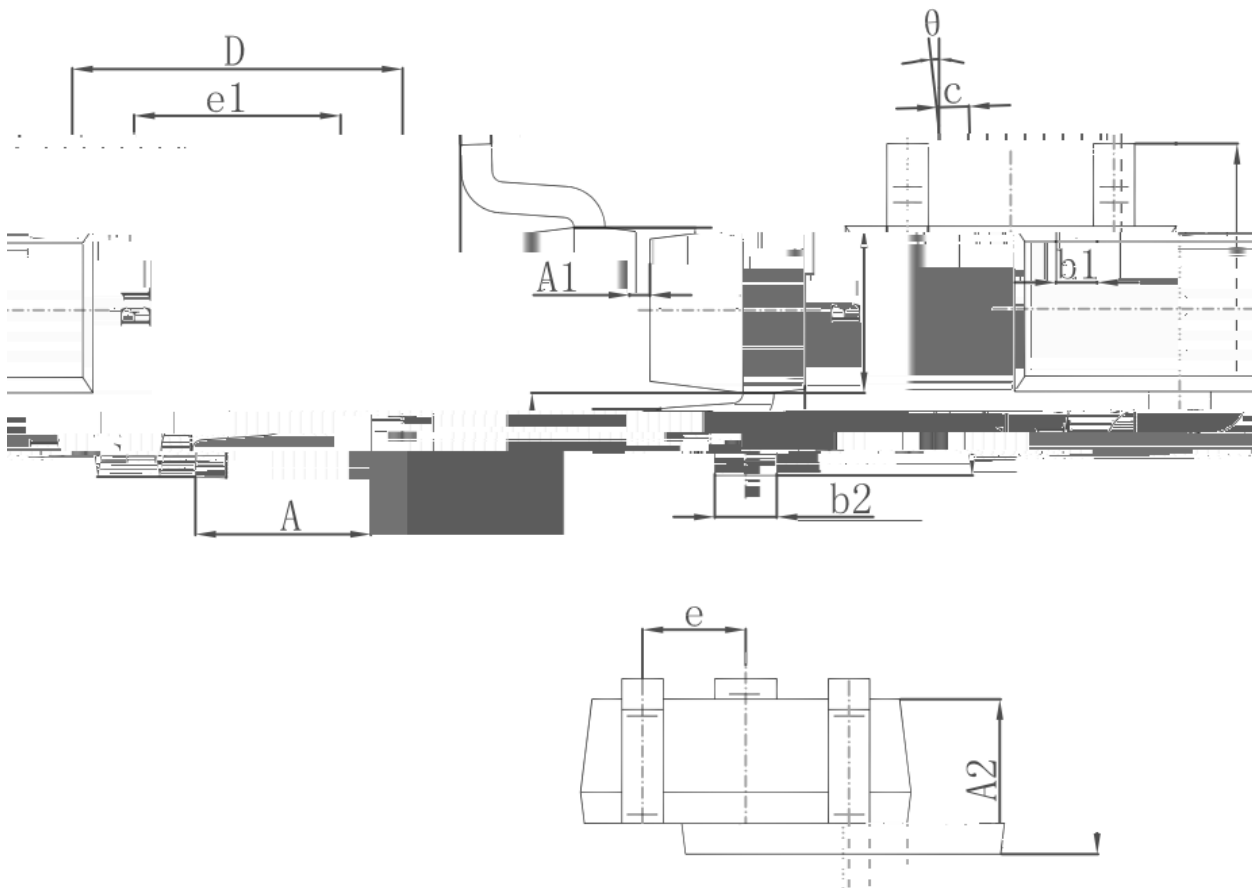
/ Electrical Characteristic Curve



/ Electrical Characteristic Curve

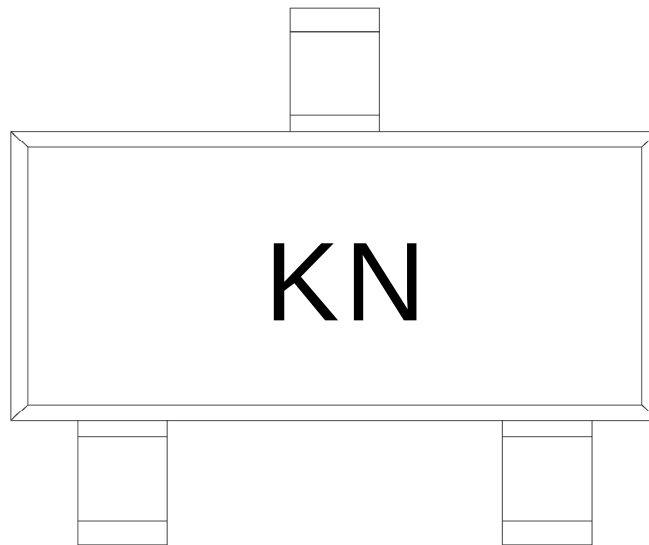


/ Package Dimensions



Dimensions In Inches		Symbol	Dimensions In Millimeters	
Min.	Max.		Min.	Max.
0.028	0.035	A	0.700	0.900
0.031	0.035	A2	0.700	0.800
0.025	0.030	F	0.200	0.280
0.145	0.175		0.057	0.069
0.500 IMP.	1.100		0.020 IMP.	0.043
0.400 REF.			0.016 REF.	
0.260	0.460		0.010	0.018
0°	8°		0°	8°

/ Marking Instructions



KN

Note:

KN: Product Type Code

() / Temperature Profile for IR Reflow Soldering(Pb-Free)

- Note:

1

150 180

60 90sec;

2

245±5

5±0.5sec;

3

2 10 /sec.
- 1.Preheating:150~180 , Time:60~90sec.

2.Peak Temp.:245±5 , Duration:5±0.5sec.

3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

605±5 (/ -5.7(Packagling)24286(SPEC.())J/T7 1 Tf03.4485 32.3713 TD.0004 Tc-35.65309:602513T